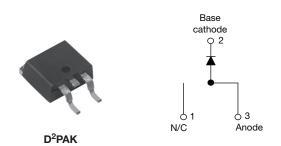
Vishay Semiconductors

High Performance Schottky Rectifier, 15 A



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PRODUCT SUMMARY				
Package	D ² PAK			
I _{F(AV)}	15 A			
V _R	60 V			
V _F at I _F	0.56 V			
I _{RM} max.	45 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Single die			
E _{AS}	6 mJ			

FEATURES

- 150 °C T_J operation
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



FREE

- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-15TQ060SPbF Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATING	MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	15	А				
V _{RRM}		60	V				
I _{FSM}	t _p = 5 μs sine	1000	А				
V _F	15 A _{pk} , T _J = 125 °C	0.56	V				
TJ	Range	-55 to +150	°C				

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-15TQ060SPbF	UNITS
Maximum DC reverse voltage	V _R	60	V
Maximum working peak reverse voltage	V _{RWM}	80	v

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 104 °C	15	А	
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	1000	А
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	260	~
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.5 A, L = 11.5	mH	6	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximu		1.50	A

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ELECTRICAL SPECIFICATIONS				
SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
	15 A	T _ 25 °C	0.62	
V (1)	30 A	1j=25 C	0.82	- V
VFM \''	15 A	T _ 125 °C	0.56	v
	30 A	1j=125 C	0.71	
I (1)	T _J = 25 °C	V - Reted V	0.80	m (
IRM (''	T _J = 125 °C	$v_{\rm R}$ = naleu $v_{\rm R}$	45	mA
C _T	$V_R = 5 V_{DC}$ (test signal ran	ge 100 kHz to 1 MHz), 25 °C	720	pF
L _S	Measured lead to lead 5 r	8.0	nH	
dV/dt	Rated V _R		10 000	V/µs
	SYMBOL V _{FM} ⁽¹⁾ I _{RM} ⁽¹⁾ C _T L _S	SYMBOL TEST CO $V_{FM}^{(1)}$ 15 A 30 A 15 A 30 A 15 A I_{5A} 30 A I_{5} T_{J} = 25 °C T_{J} = 125 °C T_{J} = 125 °C C_{T} V_{R} = 5 V_{DC} (test signal ran L_{S} Measured lead to lead 5 m	$\begin{tabular}{ c c c c c c } \hline SYMBOL & TEST CONDITIONS \\ \hline & & & & & & & & & & & & & & \\ \hline & & & &$	$\begin{tabular}{ c c c c c } \hline SYMBOL & TEST CONDITIONS & VALUES \\ \hline SYMBOL & T_{J} = 25 \ ^{\circ}C & 0.62 \\ \hline 30 \ A & T_{J} = 25 \ ^{\circ}C & 0.82 \\ \hline 15 \ A & T_{J} = 125 \ ^{\circ}C & 0.56 \\ \hline 30 \ A & T_{J} = 125 \ ^{\circ}C & 0.71 \\ \hline I_{RM} \ ^{(1)} & T_{J} = 25 \ ^{\circ}C & V_{R} = Rated \ V_{R} & 0.80 \\ \hline T_{J} = 125 \ ^{\circ}C & 45 \\ \hline C_{T} & V_{R} = 5 \ V_{DC} \ (test signal range \ 100 \ kHz \ to \ 1 \ MHz), \ 25 \ ^{\circ}C & 720 \\ \hline L_{S} & Measured \ lead \ to \ lead \ 5 \ mm \ from \ package \ body & 8.0 \\ \hline \end{tabular}$

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECH	IANICAL	SPECIFIC	ATIONS		
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and sto temperature range	orage	T _J , T _{Stg}		-55 to +150	°C
Maximum thermal resistan	nce,	R _{thJC}	DC operation See fig. 4	3.25	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	0,70
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torgue	minimum			6 (5)	kgf · cm
Mounting torque	maximum			12 (10)	(lbf · in)
Marking device			Case style D ² PAK	15TQ	060S

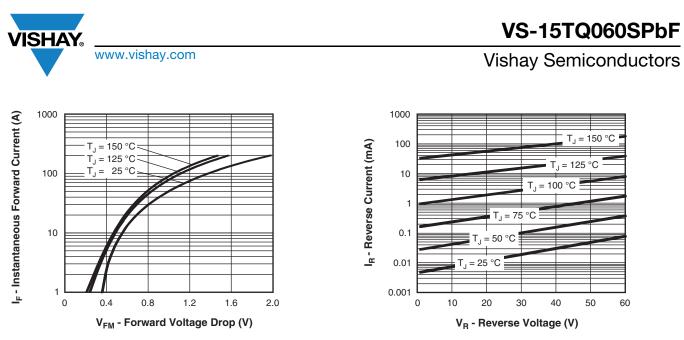


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

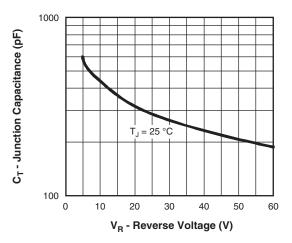


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

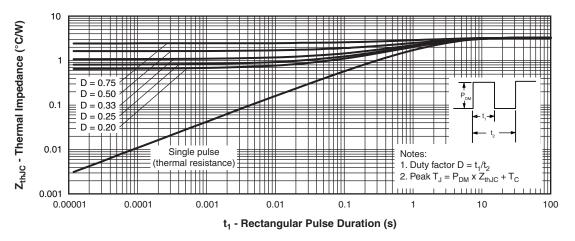
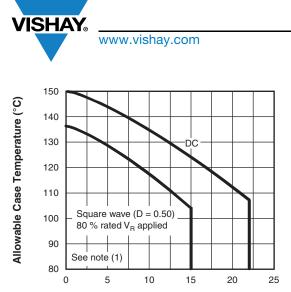


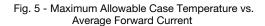
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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I_{F(AV)} - Average Forward Current (A)



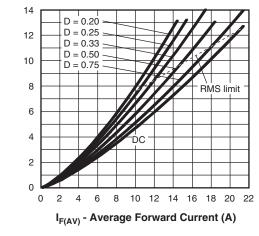
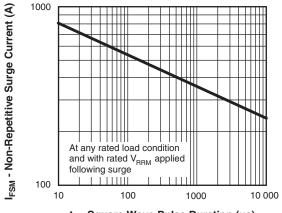


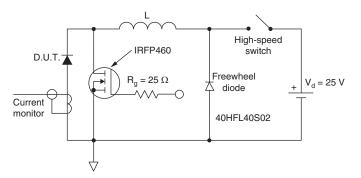
Fig. 6 - Forward Power Loss Characteristics

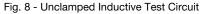


Average Power Loss (W)

t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current





Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;

 - $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

Revision: 22-Apr-14

4

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Vishay Semiconductors



ORDERING INFORMATION TABLE

Device code	VS-	15	т	Q	060	S	TRL	PbF
	1	2	3	4	5	6	(7)	8
	1 - 2 - 3 - 4 - 5 - 6 -	Cur Circ Sch Volt	nay Serr rent rati cuit conf nottky "C tage rati D ² PAK	ng (15 A iguratior ?" series ng (060	N) n: T = T(O-220		
	7 -	• T	one = tu RL = tap RR = tap	be and re	eel (left		,	
	8 -	PbF	= lead	(Pb)-fre	е			

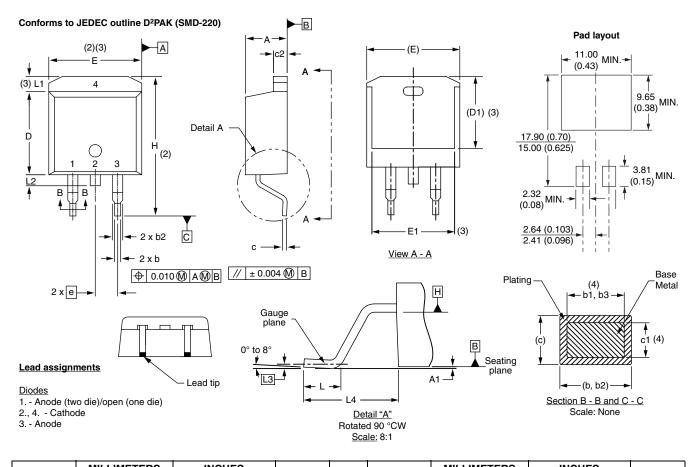
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95014		
Part marking information	www.vishay.com/doc?95008		
Packaging information	www.vishay.com/doc?95032		
SPICE model	www.vishay.com/doc?95600		

Vishay High Power Products

D²PAK, TO-262

DIMENSIONS FOR D²PAK in millimeters and inches

SHA



SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB

Notes

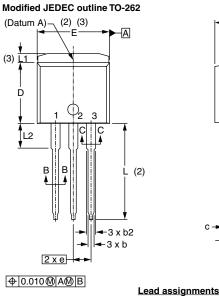
- ⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

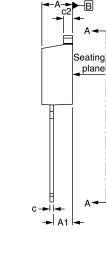
Vishay High Power Products

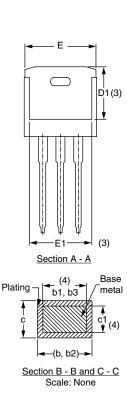
D²PAK, TO-262



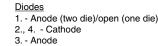
DIMENSIONS FOR TO-262 in millimeters and inches







Lead tip



OVMDOL	MILLIM	IETERS	INCH	IES	NOTEO
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	2.54 BSC		BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- ⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

⁽⁶⁾ Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

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